





### Datasheet

## HBPR-100M-60K-SI-FS(T)

Available Input Versions		1.035"-40 threaded flange for free space applications, compatible with many optical standard accessories. Optional: Fiber adapters PRA-FC, PRA-FCA, PRA-FSMA		
		25 mm dia. unthreaded flange for free space applications compatible with many optical standard accessories.		
Related Models	spectral range from 320 nm to 170 Example: FC input	fix/permanent FC fiber connector for high coupling efficiency, excellent conversion gain accuracy and common mode rejection ratio (CMRR).		
Available Accessories	PRA-FC PRA-FCA PRA-FSMA	fiber-adapter with external 1.035"-40 thread (suitable for FST models only)		
	PS-15	power supply, input: 100 - 240 VAC, output: ±15 VDC, +400/–250 mA		

## High-Speed Balanced Photoreceiver

Test conditions Transimpedance gain Gain accuracy	$\begin{split} V_S &= \pm 15 \text{ V},  T_A = 25 \text{ °C}, \text{ signal output terminated with } 50  \Omega, \\ \text{Monitor outputs terminated with } 1  M\Omega \\ 20 \text{ x } 10^3 \text{ V/A } (2^{\text{nd}} \text{ gain x4}),  60 \text{ x } 10^3 \text{ V/A } (2^{\text{nd}} \text{ gain x12}) \\ \text{switchable } (@ 50 \Omega \text{ load}) \end{split}$	
Gain accuracy		
,	±1 % electrical	
Conversion gain	10.8 x 10 <sup>3</sup> V/W typ. (@ 2 <sup>nd</sup> gain x4, 850 nm) 32.4 x 10 <sup>3</sup> V/W typ. (@ 2 <sup>nd</sup> gain x12, 850 nm)	
Common mode rejection ratio (CMRR)	50 dB typ. (f $\leq$ 100 MHz)	
Lower cut-off frequency	DC / 10 Hz, switchable	
Upper cut-off frequency	100 MHz, switchable to 20 MHz	
Rise/fall time (10 % - 90 %)	3.3 ns 17.5 ns (low pass filter 20 MHz)	
Noise equivalent power (NEP)	minimum 6.5 pW/√Hz (@ 850 nm) 7.4 pW/√Hz (@ 850 nm, 20 MHz) 12.0 pW/√Hz (@ 850 nm, 50 MHz) 19.0 pW/√Hz (@ 850 nm, 100 MHz)	
Maximum differential CW power for linear amplification	93 μW (@ 2 <sup>nd</sup> gain x4, DC-coupled, 850 nm) 31 μW (@ 2 <sup>nd</sup> gain x12, DC-coupled, 850 nm) 450 μW (@ AC-coupled, 850 nm)	
Max. optical CW balanced power (common mode power)	10 mW (on each photodiode, @ 850 nm)	
Monitor optical saturation power (limited by Maximum Rating)	12 mW (@ 850 nm)	
Detector	SI-PIN photodiode	
Active area	Ø 800 µm	
Spectral range	320 - 1000 nm	
Sensitivity	0.54 A/W typ. (@ 850 nm)	
Output voltage range	$\pm 1.0$ V (@ 50 $\Omega$ load) for linear operation and low harmonic distortion	
Max. output voltage	±2.0 V (@ 50 Ω load)	
Offset voltage compensation	$\pm 100$ mV typ., adjustable by offset potentiometer	
Output impedance	50 $\Omega$ (terminate with 50 $\Omega$ load)	
Slew rate	2000 V/µs	
Max. output current	70 mA	
Output return loss S22	−30 dB @ < 100 MHz −20 dB @ < 800 MHz	
Output noise	2.0 mV <sub>RMS</sub> (13 mV <sub>PP</sub> ) (@ 2 <sup>nd</sup> gain x4) 5.6 mV <sub>RMS</sub> (37 mV <sub>PP</sub> ) (@ 2 <sup>nd</sup> gain x12) 0.5 mV <sub>RMS</sub> (3.0 mV <sub>PP</sub> ) typ. (@ 2 <sup>nd</sup> gain x4, BW: 20 MHz) 1.3 mV <sub>RMS</sub> (8.8 mV <sub>PP</sub> ) typ. (@ 2 <sup>nd</sup> gain x12, BW: 20 MHz) (@ 50 $\Omega$ load, no signal on detectors, measurement bandwidth 2 GHz)	
	(CMRR) Lower cut-off frequency Upper cut-off frequency Rise/fall time (10 % - 90 %) Noise equivalent power (NEP) Maximum differential CW power for linear amplification Max. optical CW balanced power (common mode power) Monitor optical saturation power (limited by Maximum Rating) Detector Active area Spectral range Sensitivity Output voltage range Max. output voltage Offset voltage compensation Output impedance Slew rate Max. output current Output return loss S22	

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# High-Speed Balanced Photoreceiver

Monitor output gain	$1 \ge 10^3 \text{ V/A} \ (@ \ge 100 \text{ k}\Omega \text{ load})$			
Monitor output voltage range	0 +10 V (@ ≥ 100 kΩ load)			
	50 $\Omega$ (terminate with $\geq$ 100 k $\Omega$ load)			
Monitor output max. output current	30 mA typ.			
Monitor output bandwidth	DC 10 MHz			
Monitor output noise	$0.6 \text{ mV}_{\text{RMS}} (4 \text{ mV}_{\text{PP}})$ (@ 100 k $\Omega$ load, no measurement band	o signal on detectors, width 200 MHz)		
Material	1.4305 stainless steel, nickel-plated (FST flange) AIMg4.5Mn, nickel-plated (FS flange)			
Material	1.4305 stainless steel, glass bead blasted			
Supply voltage	±15 V (±14.5 V ±16.5 V)			
Supply current	$-90$ / $+120$ mA (depends on operating conditions, recommended power supply capability min. $\pm 200$ mA)			
Weight	410 g (0.9 lbs)	410 g (0.9 lbs)		
Material	AIMg3Mn, nickel-plated			
Storage temperature	−40 +85 °C			
Operating temperature	0 +60 °C			
Max. CW power (averaged)	12 mW (on each photodiode)			
Power supply voltage	±20 V			
Input	FS version	25 mm dia. unthreaded flange for free space applications		
	FST version	1.035"-40 threaded flange for free space applications and for use with various types of optical standard accessories		
Output	SMA jack (female)			
Power supply		Lemo <sup>®</sup> series 1S, 3-pin fixed socket (mating plug type: FFA.1S.303.CLAC52)		
P 		<sup>®</sup> Pin 2: −15 V <sub>13</sub> Pin 3: GND		
HBPR-100M-60K-SI, 2 x threaded coupler ring (FST version only), Lemo $^{\mbox{\tiny ®}}$ 3-pin connector, 3 x adapter SMA (male) to BNC (female), datasheet				
HBPR-100M-60K-SI-FS	25 mm dia. unthrea	ded flange for free space applications		
HBPR-100M-60K-SI-FST		I flange for free space applications and types of optical standard accessories		
	Monitor output voltage range Monitor output impedance Monitor output max. output current Monitor output bandwidth Monitor output noise Material Supply voltage Supply current Weight Material Storage temperature Operating temperature Operating temperature Max. CW power (averaged) Power supply voltage Input Maxer supply voltage	Monitor output voltage range Monitor output impedance Monitor output max. output current $0 \dots +10 \ V (@ \ge 10)$ $50 \ \Omega$ (terminate with $30 \ mA \ typ.$ Monitor output bandwidth Monitor output noise $DC \dots 10 \ MHz$ $0.6 \ mV_{MMS} (4 \ mV_{PP})$ (@ 100 k $\Omega \ load, nomeasurement bandwidthMaterial1.4305 \ stainless \ staAlMg4.5Mn, nickel-MaterialMaterial1.4305 \ stainless \ staAlMg4.5Mn, nickel-90 \ / +120 \ mA \ (derecommended powerWeightWeight410 \ g \ (0.9 \ lbs)MaterialMaterialAlMg3Mn, nickel-plStorage temperatureOperating temperature-40 \ \dots +85 \ ^{\circ}C0 \ \dots +60 \ ^{\circ}CMax. CW power (averaged)Power supply voltage12 \ mW (on each ph\pm 20 \ VInputFS versionOutputSMA jack (female)Power supply voltagePower supplyLemo® series 1S, 3(mating plug type: F\frac{W \ 2}{V} \ even \ supplyHBPR-100M-60K-SI, 2 x threaded coupler ring (FST versionHBPR-100M-60K-SI-FS1.035"-40 threadedHBPR-100M-60K-SI-FSTHBPR-100M-60K-SI-FST1.035"-40 threaded$		



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